TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT process)

2SA1202

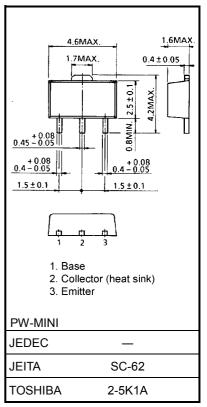
Power Amplifier Applications Voltage Amplifier Applications

- Suitable for driver of 30 to 35 watts audio amplifier
- Small flat package
- $P_C = 1.0$ to 2.0 W (mounted on ceramic substrate)
- Complementary to 2SC2882

Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit	
Collector-base voltage	V _{CBO}	-80	V	
Collector-emitter voltage	V _{CEO}	-80	V	
Emitter-base voltage	V _{EBO}	-5	V	
Collector current	Ι _C	-400	mA	
Base current	Ι _Β	-80	mA	
Collector power dissipation	P _C	500	mW	
	P _C	1000		
	(Note 1)	1000		
Junction temperature	Tj	150	°C	
Storage temperature range	T _{stg}	-55 to 150	°C	

Note 1: Mounted on ceramic substrate (250 mm² × 0.8 t)



Weight: 0.05 g (typ.)

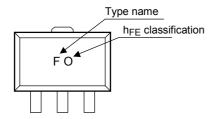
Unit: mm

Electrical Characteristics (Ta = 25°C)

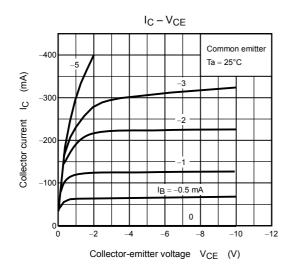
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	V _{CB} = -80 V, I _E = 0	—	_	-0.1	μA
Emitter cut-off current	I _{EBO}	$V_{EB} = -5 V, I_C = 0$	_		-0.1	μA
Collector-emitter breakdown voltage	V (BR) CEO	$I_{\rm C}$ = -10 mA, $I_{\rm B}$ = 0	-80	-	-	V
DC current gain	h _{FE (1)} (Note 2)	I _E = −2 mA, I _C = −50 mA	70	_	240	
	h _{FE (2)}	V _{CE} = -2 V, I _C = -200 mA	40		-	
Collector-emitter saturation voltage	V _{CE (sat)}	I _C = -200 mA, I _B = -20 mA	_		-0.4	V
Base-emitter voltage	V _{BE}	$V_{CE} = -2 V, I_C = -5 mA$	-0.55	_	-0.8	V
Transition frequency	f _T	V _{CE} = -10 V, I _C = -10 mA	—	120	_	MHz
Collector output capacitance	C _{ob}	V _{CB} = −10 V, I _E = 0, f = 1 MHz	_	14	_	pF

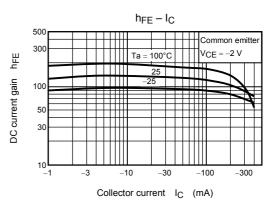
Note 2: $h_{FE(1)}$ classification O: 70 to 140, Y: 120 to 240

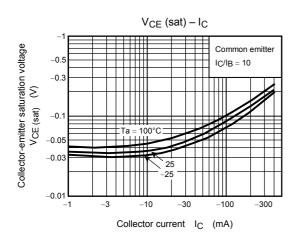
Marking

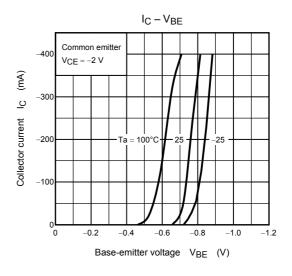


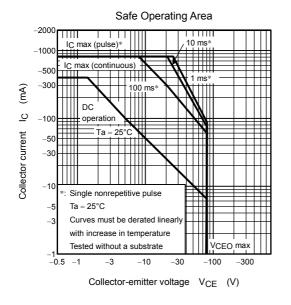
TOSHIBA

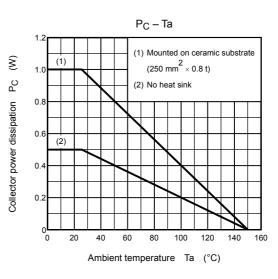












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